

180V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN TO252
Features

- $BV_{CEO} > 180V$
- $I_C = 0.5A$ high Continuous Collector Current
- $I_{CM} = 1A$ Peak Pulse Current
- High gain device > 500 at $I_C = 100mA$
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

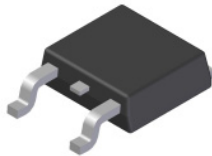
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.34 grams (approximate)

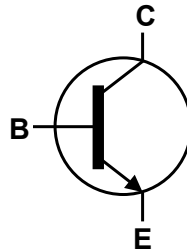
Applications

- Voltage Regulator Transistors
- Startup Switches
- Darlington Replacement
- DC Fans
- Relays and Solenoid Driving

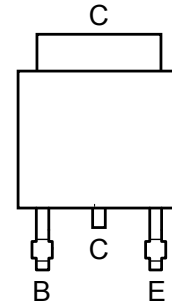
TO252 (DPAK)



Top View



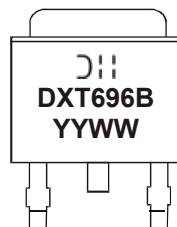
Equivalent Circuit


 Top View
Pin-Out

Ordering Information (Note 4)

Product	Package	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DXT696BK-13	TO252 (DPAK)	DXT696B	13	16	2,500

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 3. Halogen and Antimony free "Green" products are defined as those which contain $<900ppm$ bromine, $<900ppm$ chlorine ($<1500ppm$ total Br + Cl) and $<1000ppm$ antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>

Marking Information


DII = Manufacturers' code marking
 DXT 696B = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Digit of Year, (ex: 13 = 2013)
 WW = Week Code 01 - 52

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	180	V
Collector-Emitter Voltage	V _{CEO}	180	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	0.5	A
Peak Pulse Current	I _{CM}	1	A
Peak Base Current	I _{BM}	0.5	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

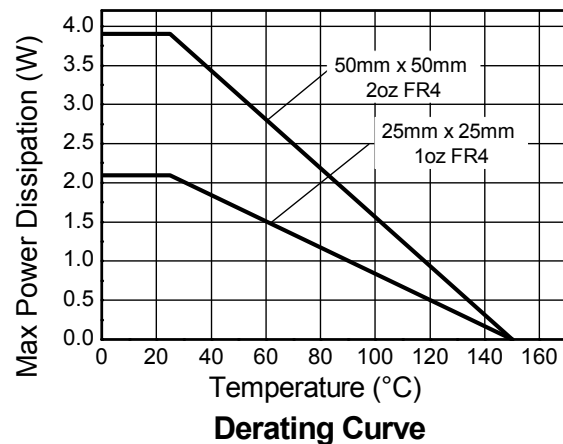
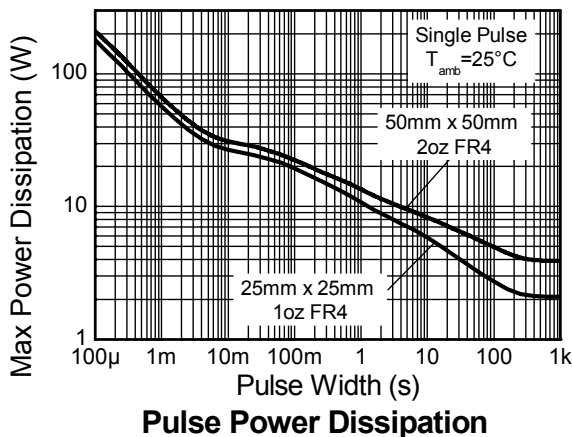
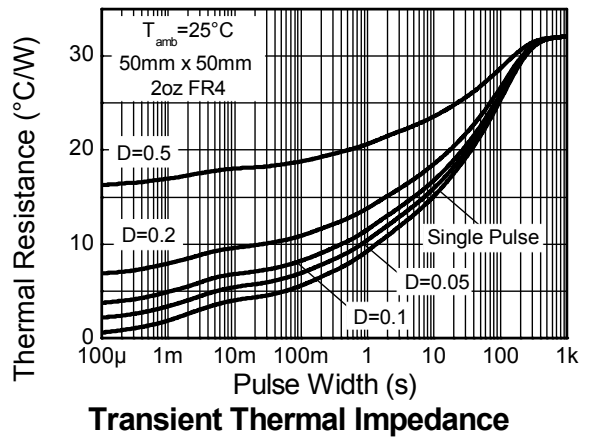
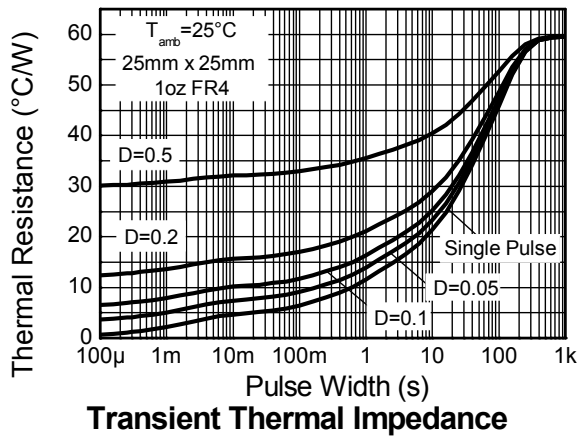
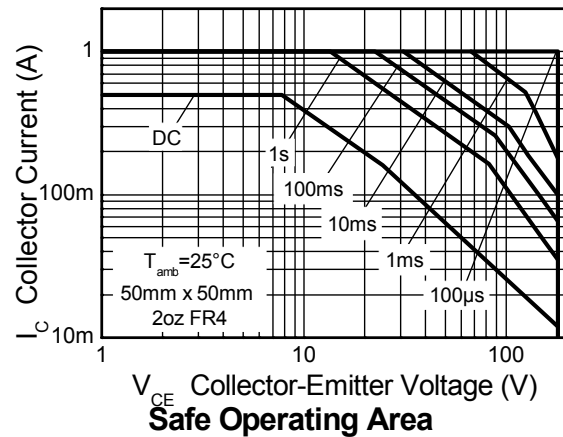
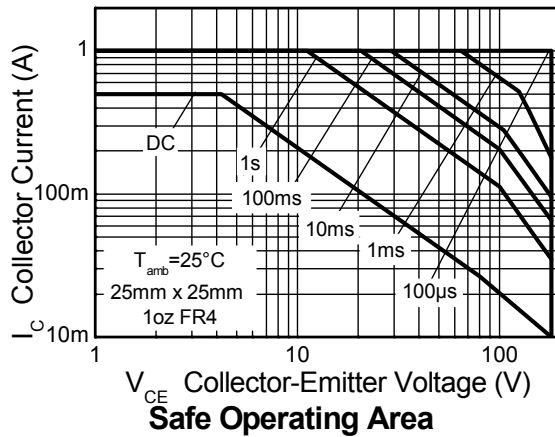
Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	3.9	W
		2.1	
		1.6	
Thermal Resistance, Junction to Ambient Air	R _{θJA}	32	°C/W
		59	
		80	
Thermal Resistance, Junction to Leads	R _{θJL}	8.4	°C/W
Thermal Resistance, Junction to Case	R _{θJC}	14.6	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
- For a device mounted with the exposed collector pad on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Same as note (5), except mounted on 25mm x 25mm 1oz copper.
 - Same as note (5), except mounted on minimum recommended pad (MRP) layout.
 - Thermal resistance from junction to solder-point (on the exposed collector pad).
 - Thermal resistance from junction to the top of the case.
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

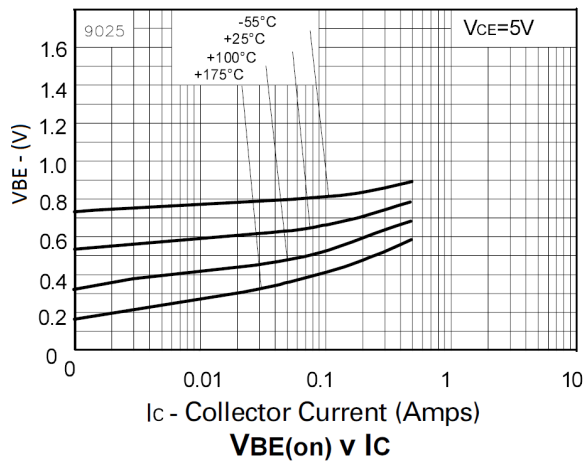
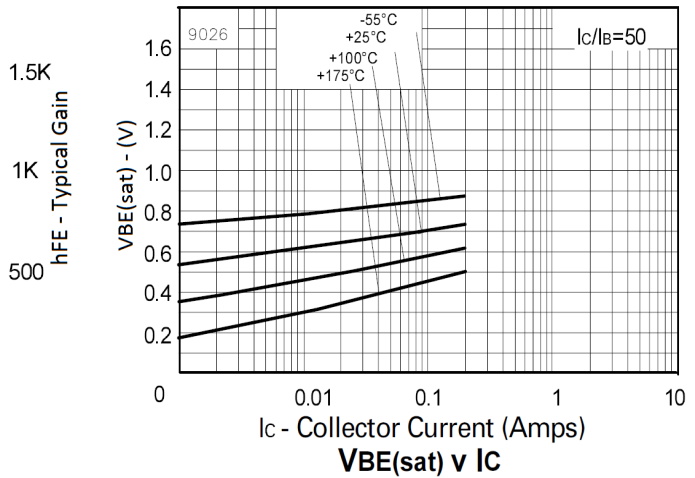
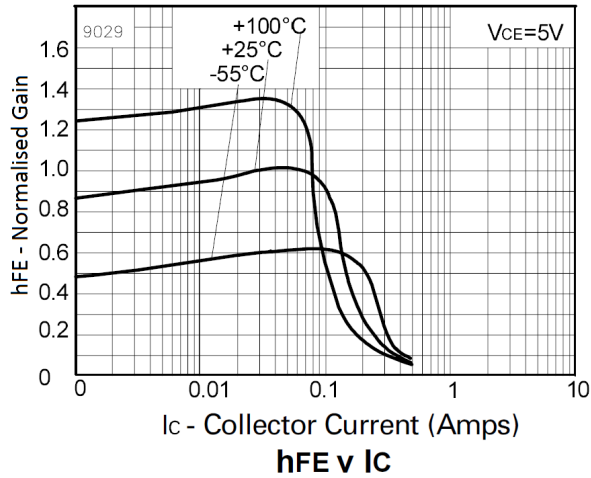
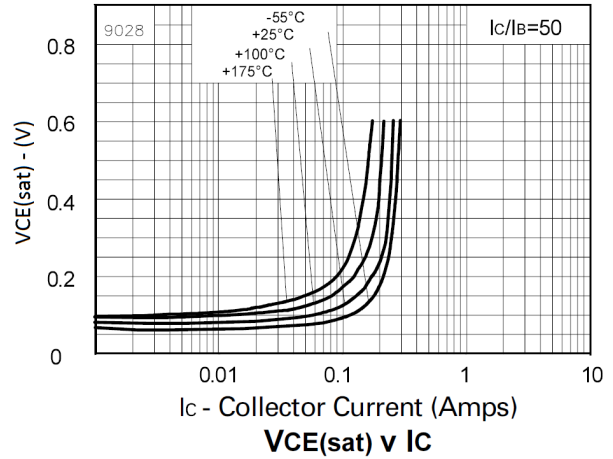
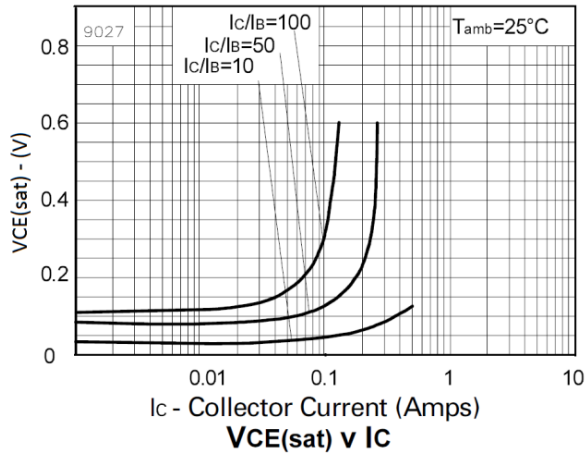


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	180	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	180	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	—	—	V	I _E = 100μA
Collector-Base Cutoff Current	I _{CBO}	—	—	100	nA	V _{CB} = 140V
Emitter Cutoff Current	I _{EBO}	—	—	100	nA	V _{EB} = 5V
DC Current Gain (Note 11)	h _{FE}	500 150	— —	— —		I _C = 100mA, V _{CE} = 5V I _C = 200mA, V _{CE} = 5V
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	— — —	— — —	200 200 250	mV	I _C = 50mA, I _B = 0.5mA I _C = 100mA, I _B = 2.0mA I _C = 200mA, I _B = 5.0mA
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	—	—	900	mV	I _C = 200mA, I _B = 5mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	—	—	900	mV	I _C = 200mA, V _{CE} = 5V
Input Capacitance	C _{ibo}	—	200	—	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	C _{obo}	—	6	—	pF	V _{CE} = 10V, f = 1MHz
Current Gain-Bandwidth Product	f _T	70	—	—	MHz	V _{CE} = 5V, I _C = 50mA, f=50MHz
Turn-On Time	t _{on}	—	80	—	ns	V _{CC} = 50V, I _C = 100mA
Turn-Off Time	t _{off}	—	4,400	—	ns	I _{B1} = -I _{B2} = 10mA

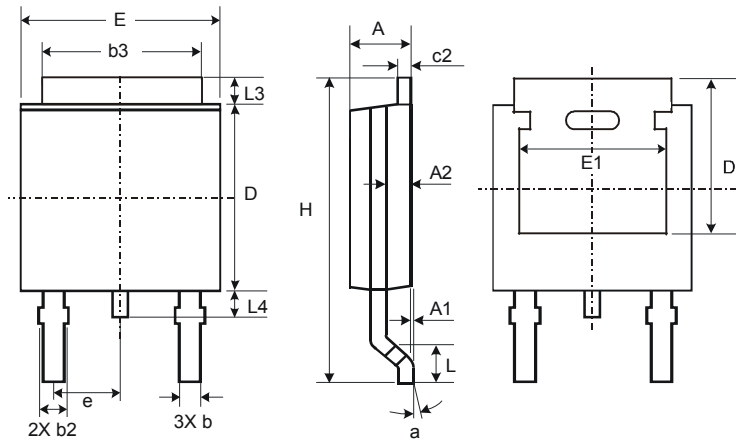
Note: 11. Measured under pulsed conditions. Pulse width ≤ 300 μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



Package Outline Dimensions

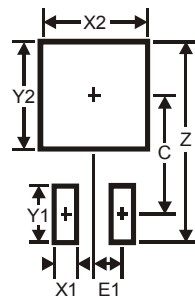
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



TO252			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.46	5.33
c2	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	—	—
e	—	—	2.286
E	6.45	6.70	6.58
E1	4.32	—	—
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	—
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
C	6.9
E1	2.3

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

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